# NSN 5961-01-315-8992

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-315-8992

#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

0.450 inches

#### **Overall Width:**

1.050 inches

## Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact-darlington connected

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

### Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### **Features Provided:**

Hermetically sealed case and electrostatic sensitive

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

2.0 collector to emitter voltage, dc

#### **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

#### **Transfer Ratio:**

30.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

--

## Demilitarization:

No

Fiig:

A110a0